SPICE Device Model Si3430DV



Vishay Siliconix

N-Channel 100 V (D-S) MOSFET

DESCRIPTION

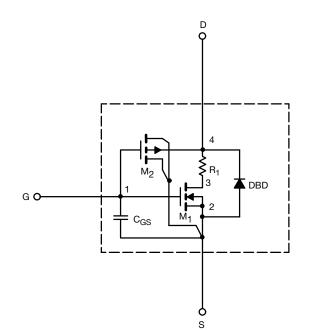
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	-	TYPICAL	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	-	3	V
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	-	34	А
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.4 \text{ A}$	-	0.146	Ω
		$V_{GS} = 6 \text{ V}, \text{ I}_{D} = 2.3 \text{ A}$	-	0.154	
Forward Transconductance ^a	g _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 2.4 \text{ A}$	-	8.1	S
Diode Forward Voltage ^a	V _{SD}	$I_{S} = 1.7 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.72	V
Dynamic ^b					
Total Gate Charge ^b	Qg	V_{DS} = 50 V, V_{GS} = 10 V, I_{D} = 2.4 A	-	6.06	nC
Gate-Source Charge ^b	Q _{gs}		-	1.5	
Gate-Drain Charge ^b	Q _{gd}		-	1.4	
Turn-On Delay Time	t _{d(on)}	$\label{eq:V_DD} \begin{array}{l} V_{\text{DD}} = 50 \ \text{V}, \ R_{\text{L}} = 50 \ \Omega \\ I_{\text{D}} = 1 \ \text{A}, \ V_{\text{GEN}} = 10 \ \text{V}, \ R_{\text{g}} = 6 \ \Omega \end{array}$	-	8	ns
Rise Time ^b	tr		-	10	
Turn-Off Delay Time ^b	t _{d(off)}		-	23	
Fall Time ^b	t _f		-	30	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.7 A, dl/dt = 100 A/μs	-	52	ns

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.



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55°C

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VGS

4

5

4

6

8

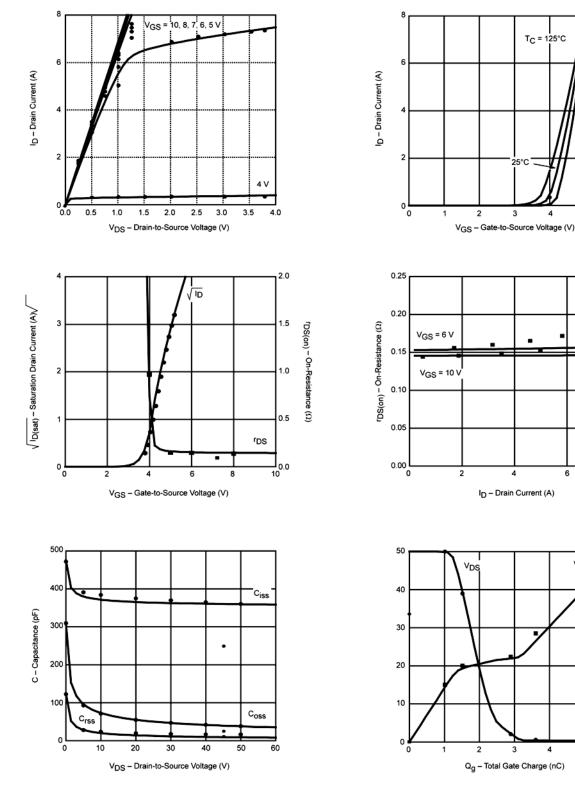
10

6

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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data.

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